



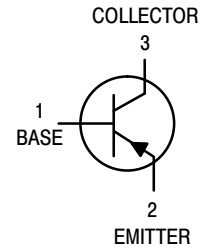
**THE DATASHEET OF
SBC807-16LT1G**



General Purpose Transistors

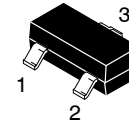
PNP Silicon

BC807-16L, BC807-25L, BC807-40L



Features

- S Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant



SOT-23
CASE 318
STYLE 6

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector – Emitter Voltage	V_{CEO}	-45	V
Collector – Base Voltage	V_{CBO}	-50	V
Emitter – Base Voltage	V_{EBO}	-6.0	V
Collector Current – Continuous	I_C	-500	mAdc

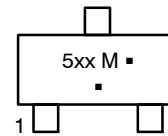
THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation FR-5 Board, (Note 1) $T_A = 25^\circ\text{C}$ Derate above 25°C	P_D	225 1.8	mW mW/ $^\circ\text{C}$
Thermal Resistance, Junction-to-Ambient (Note 1)	$R_{\theta JA}$	436	$^\circ\text{C}/\text{W}$
Total Device Dissipation Alumina Substrate, (Note 1) $T_A = 25^\circ\text{C}$ Derate above 25°C	P_D	300 2.4	mW mW/ $^\circ\text{C}$
Thermal Resistance, Junction-to-Ambient (Note 2)	$R_{\theta JA}$	417	$^\circ\text{C}/\text{W}$
Junction and Storage Temperature	T_J, T_{stg}	-55 to +150	$^\circ\text{C}$

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. FR-4 Board, 1 oz. Cu, 100mm².
2. Alumina = 0.4 x 0.3 x 0.024 in 99.5% alumina.

MARKING DIAGRAM



- 5xx = Device Code
xx = A1, B1, or C
- M = Date Code*
- = Pb-Free Package

(Note: Microdot may be in either location)

*Date Code orientation and/or overbar may vary depending upon manufacturing location.

ORDERING INFORMATION

See detailed ordering and shipping information on page 2 of this data sheet.

BC807-16L, BC807-25L, BC807-40L

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted.)

Characteristic	Symbol	Min	Typ	Max	Unit
OFF CHARACTERISTICS					
Collector – Emitter Breakdown Voltage (I _C = -10 mA)	V _{(BR)CEO}	-45	-	-	V
Collector – Emitter Breakdown Voltage (V _{EB} = 0, I _C = -10 μA)	V _{(BR)CES}	-50	-	-	V
Emitter – Base Breakdown Voltage (I _E = -1.0 μA)	V _{(BR)EBO}	-6.0	-	-	V
Collector Cutoff Current (V _{CB} = -20 V) (V _{CB} = -20 V, T _J = 150°C)	I _{CBO}	-	-	-100 -5.0	nA μA

ON CHARACTERISTICS

DC Current Gain (I _C = -100 mA, V _{CE} = -1.0 V) (I _C = -500 mA, V _{CE} = -1.0 V)	BC807-16, SBC80-16L BC807-25, SBC807-25L BC807-40, SBC807-40L h _{FE}	100 160 250 40	- - - -	250 400 600 -	-
Collector – Emitter Saturation Voltage (I _C = -500 mA, I _B = -50 mA)	V _{CE(sat)}	-	-	-0.7	V
Base – Emitter On Voltage (I _C = -500 mA, V _{CE} = -1.0 V)	V _{BE(on)}	-	-	-1.2	V

SMALL-SIGNAL CHARACTERISTICS

Current – Gain – Bandwidth Product (I _C = -10 mA, V _{CE} = -5.0 Vdc, f = 100 MHz)	f _T	100	-	-	MHz
Output Capacitance (V _{CB} = -10 V, f = 1.0 MHz)	C _{obo}	-	10	-	pF

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

ORDERING INFORMATION

Device	Specific Marking	Package	Shipping [†]
BC807-16LT1G	5A1	SOT-23 (Pb-Free)	3000 / Tape & Reel
SBC807-16LT1G*			
BC807-16LT3G	5A1		10,000 / Tape & Reel
SBC807-16LT3G*			
BC807-25LT1G	5B1		3000 / Tape & Reel
SBC807-25LT1G*			
BC807-25LT3G	5B1		10,000 / Tape & Reel
SBC807-25LT3G*			
BC807-40LT1G	5C		3000 / Tape & Reel
SBC807-40LT1G*			
BC807-40LT3G	5C	10,000 / Tape & Reel	
SBC807-40LT3G*			

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

*S Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable.

TYPICAL CHARACTERISTICS - BC807-16LT1

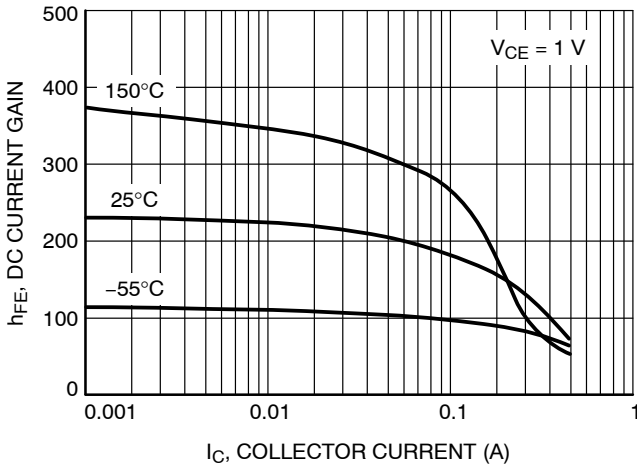


Figure 1. DC Current Gain vs. Collector Current

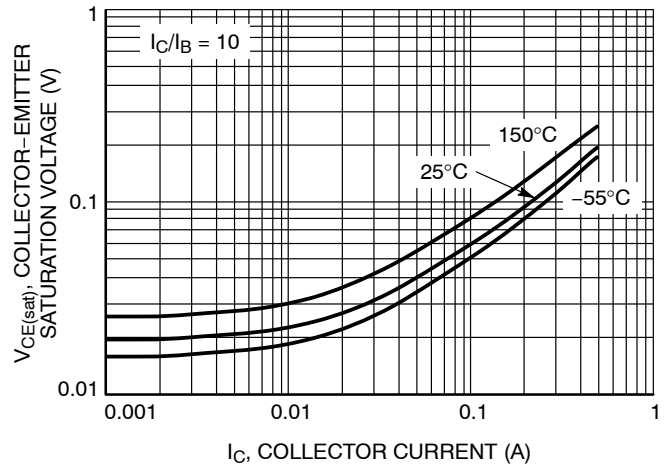


Figure 2. Collector Emitter Saturation Voltage vs. Collector Current

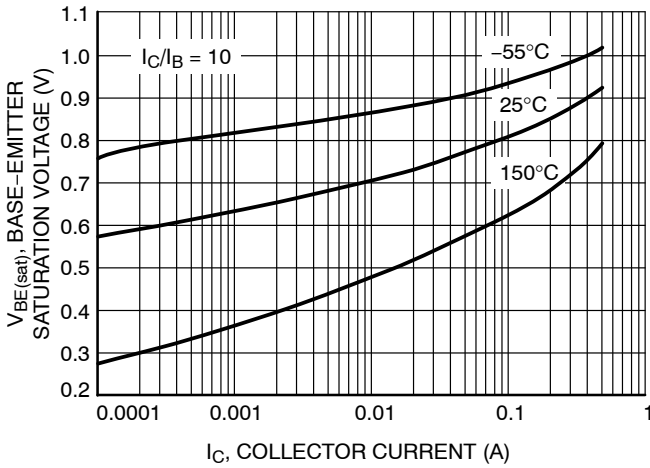


Figure 3. Base Emitter Saturation Voltage vs. Collector Current

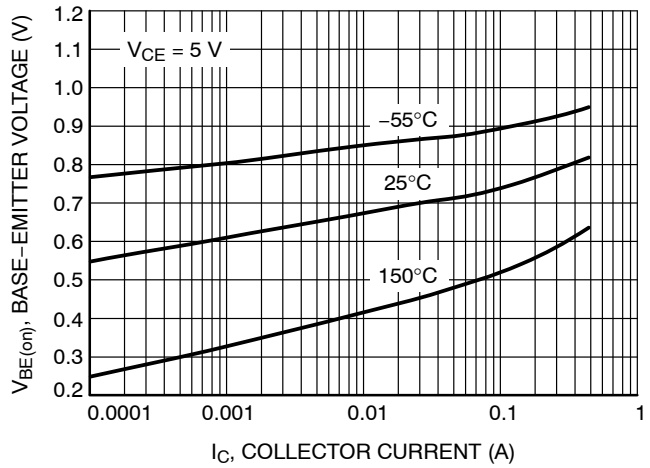


Figure 4. Base Emitter Voltage vs. Collector Current

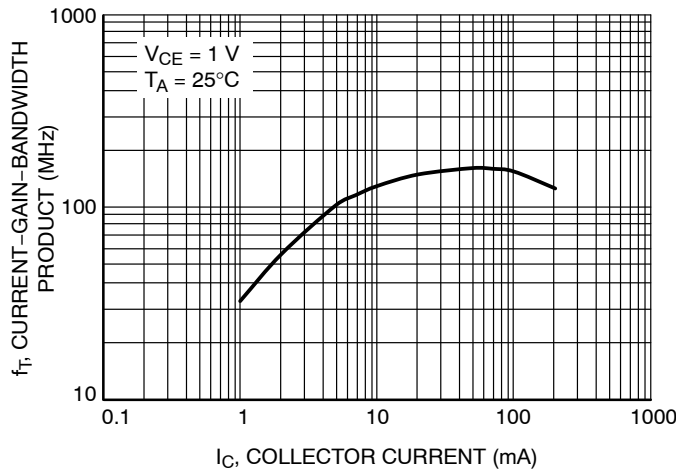


Figure 5. Current Gain Bandwidth Product vs. Collector Current

TYPICAL CHARACTERISTICS – BC807-16LT1

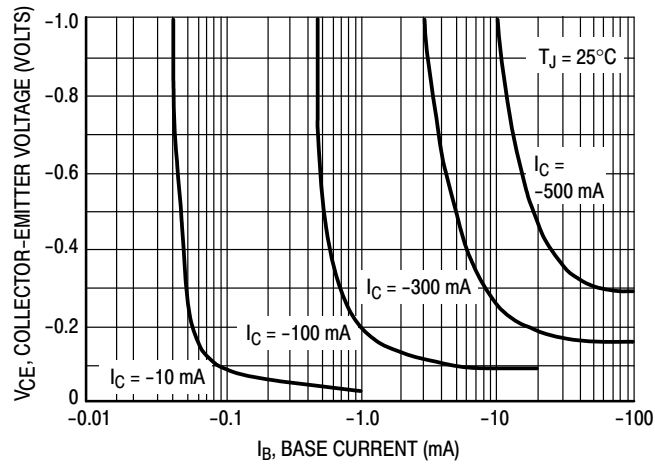


Figure 6. Saturation Region

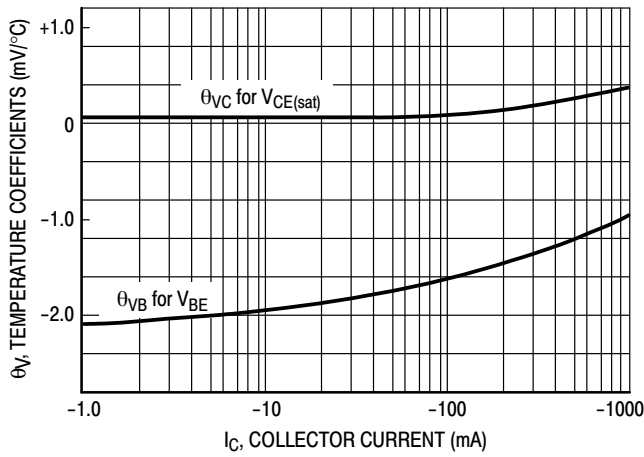


Figure 7. Temperature Coefficients

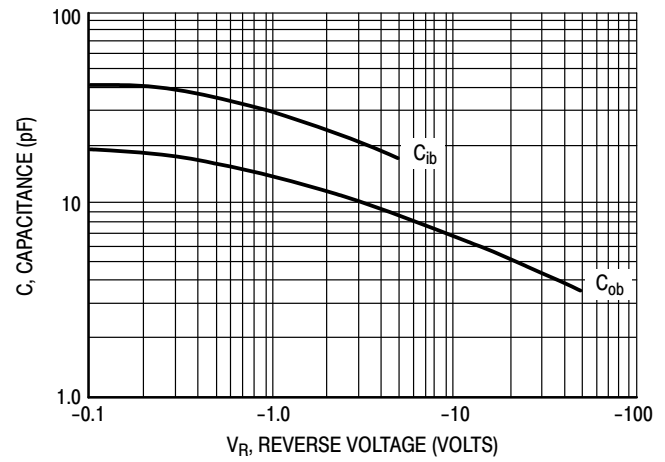


Figure 8. Capacitances

TYPICAL CHARACTERISTICS - BC807-25LT1

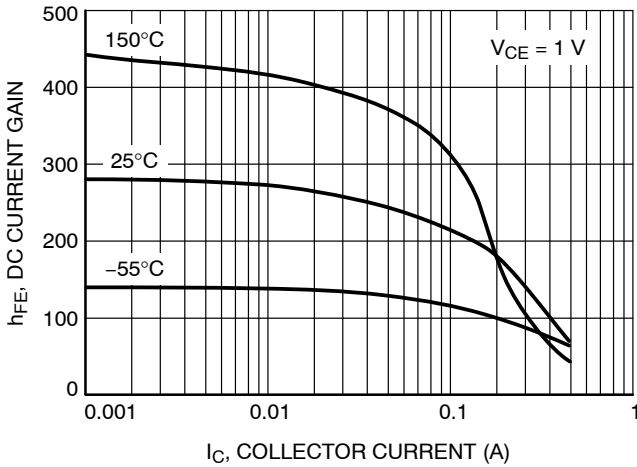


Figure 9. DC Current Gain vs. Collector Current

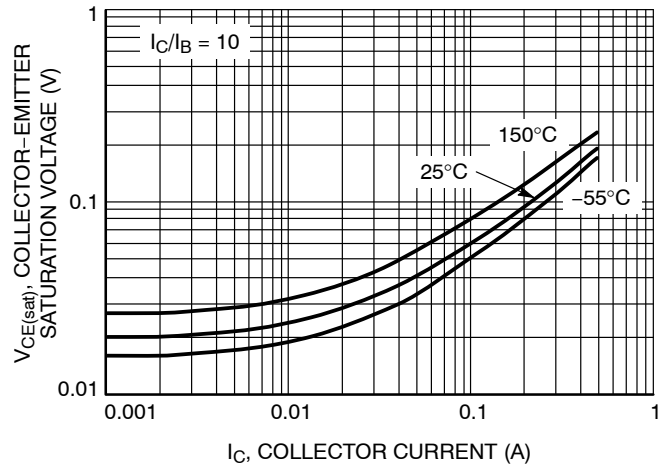


Figure 10. Collector Emitter Saturation Voltage vs. Collector Current

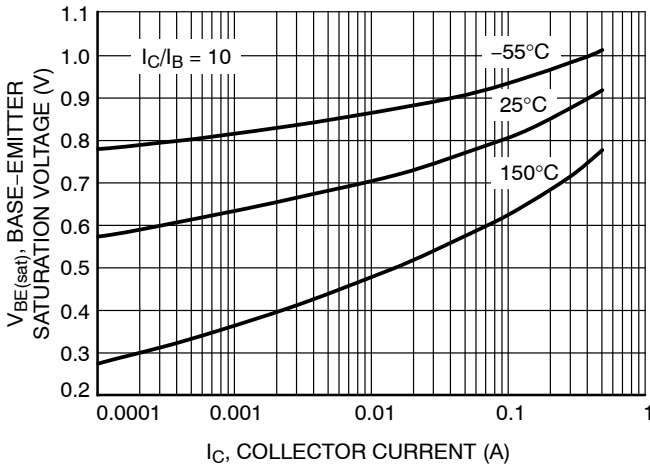


Figure 11. Base Emitter Saturation Voltage vs. Collector Current

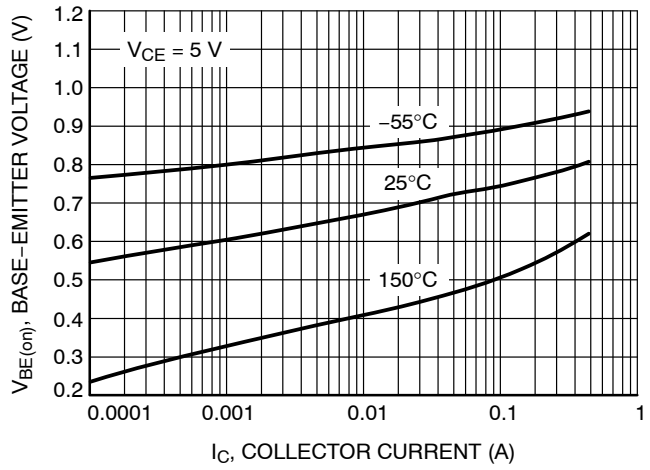


Figure 12. Base Emitter Voltage vs. Collector Current

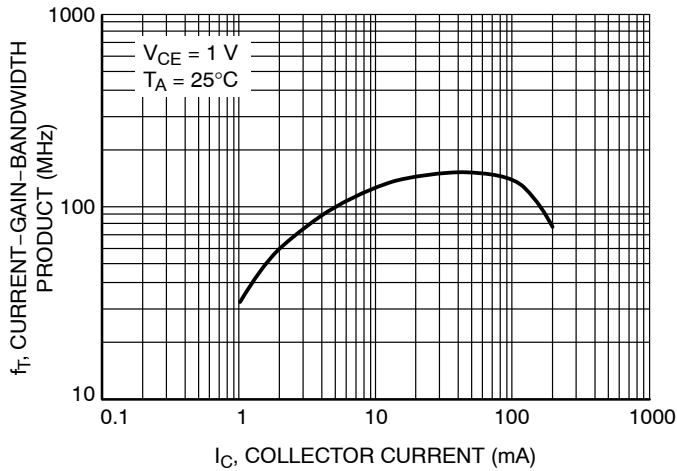


Figure 13. Current Gain Bandwidth Product vs. Collector Current

TYPICAL CHARACTERISTICS – BC807-25LT1

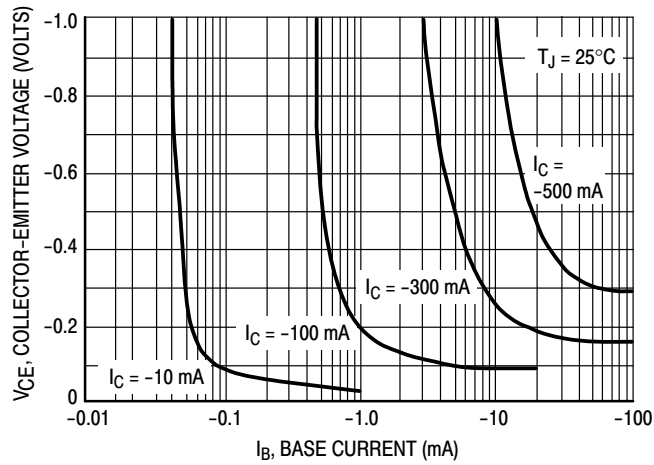


Figure 14. Saturation Region

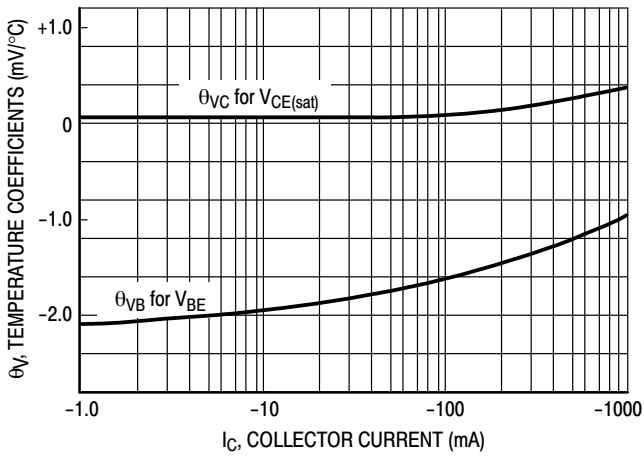


Figure 15. Temperature Coefficients

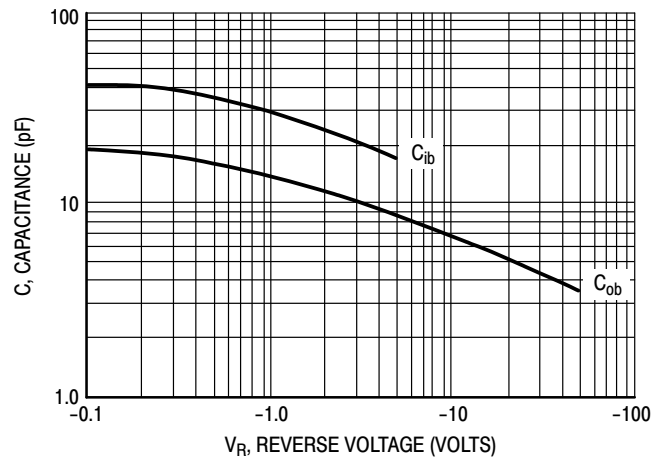


Figure 16. Capacitances

TYPICAL CHARACTERISTICS – BC807-40LT1

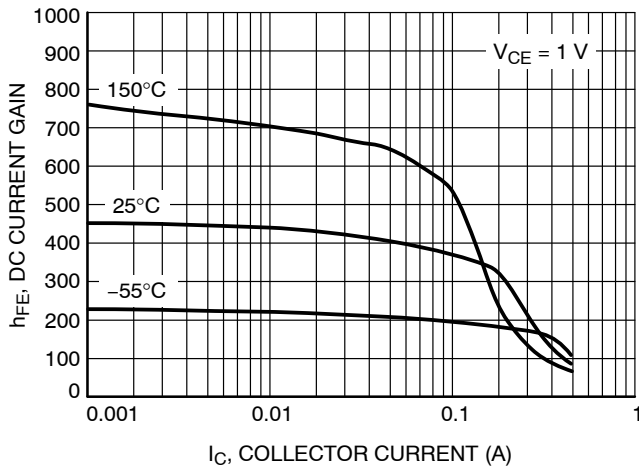


Figure 17. DC Current Gain vs. Collector Current

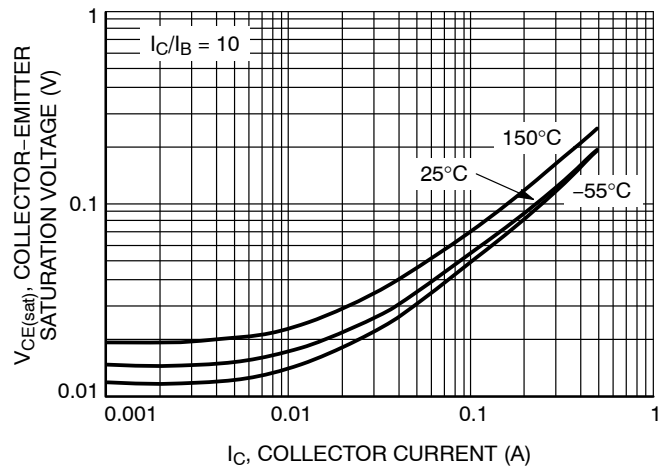


Figure 18. Collector Emitter Saturation Voltage vs. Collector Current

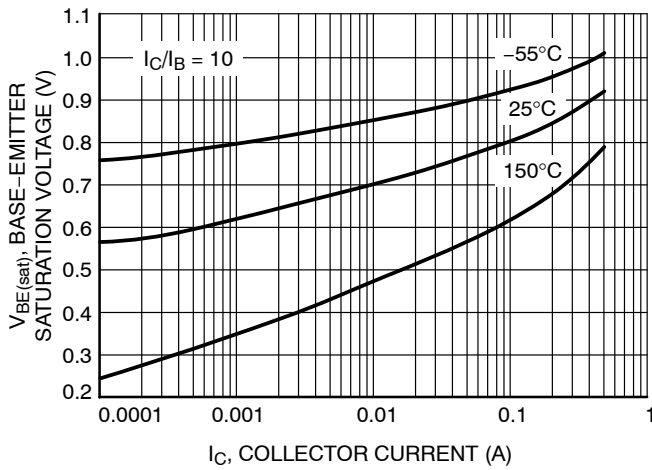


Figure 19. Base Emitter Saturation Voltage vs. Collector Current

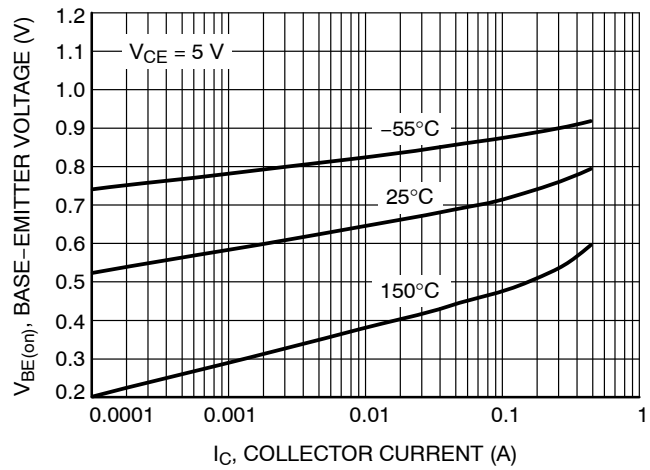


Figure 20. Base Emitter Voltage vs. Collector Current

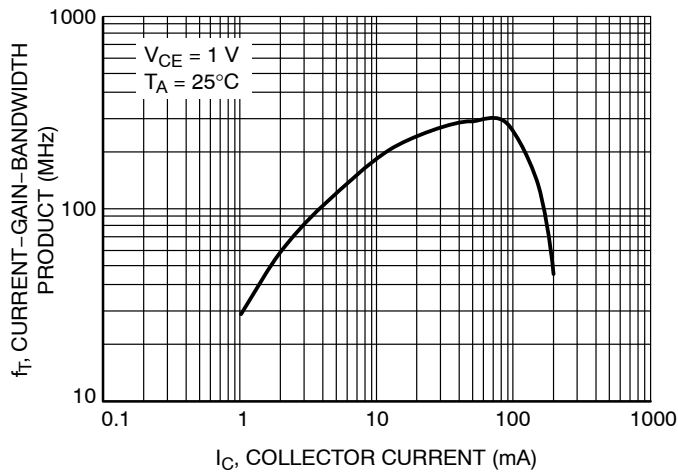


Figure 21. Current Gain Bandwidth Product vs. Collector Current

TYPICAL CHARACTERISTICS - BC807-40LT1

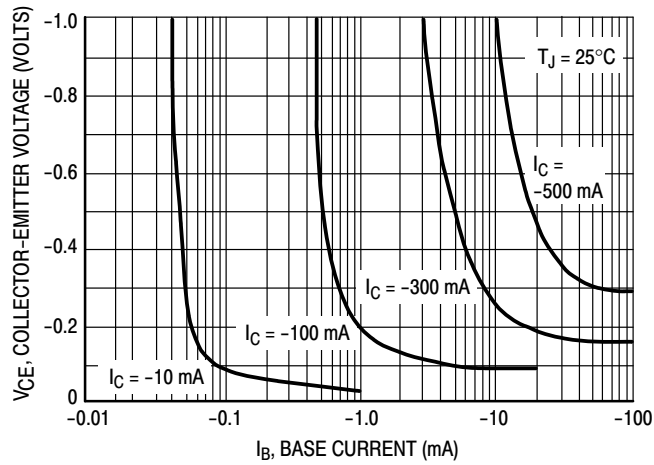


Figure 22. Saturation Region

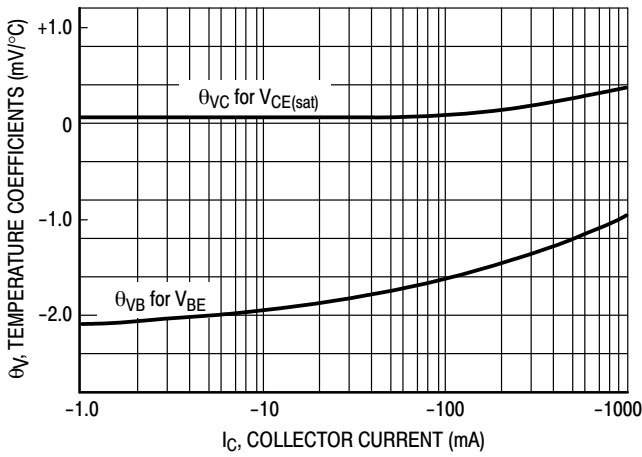


Figure 23. Temperature Coefficients

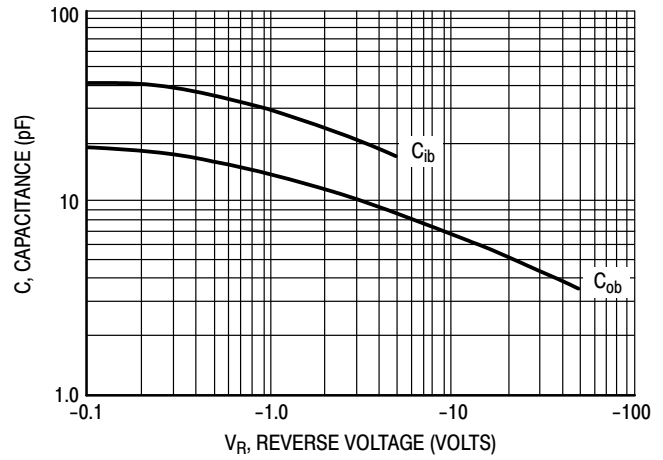


Figure 24. Capacitances

BC807-16L, BC807-25L, BC807-40L

TYPICAL CHARACTERISTICS – BC807-16LT1, BC807-25LT1, BC807-40LT1

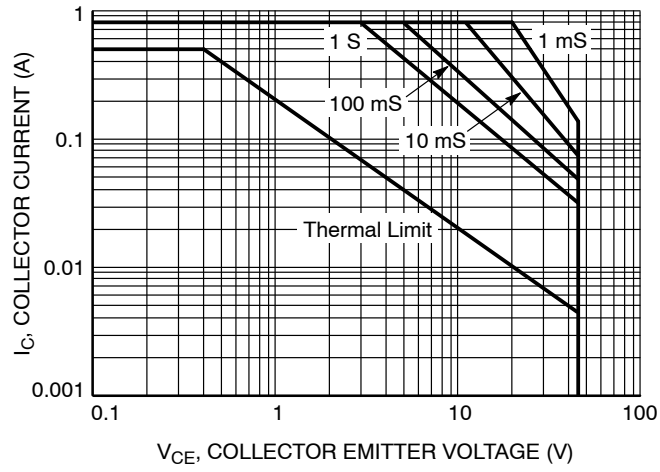


Figure 25. Safe Operating Area

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